InGaP HBT Gain Block

Product Features

- DC 6000 MHz
- +19 dBm P1dB at 900 MHz
- +33.5 dBm OIP3 at 900 MHz
- 14 dB Gain at 900 MHz
- Single Voltage Supply
- Green SOT-86 SMT Package
- Internally matched to 50 Ω

Applications

- Mobile Infrastructure
- CATV / DBS
- W-LAN / ISM
- RFID
- Defense / Homeland Security
- Fixed Wireless

Product Description

The AG602-86 is a general-purpose buffer amplifier that offers high dynamic range in a low-cost surface-mount package. At 900 MHz, the AG602-86 typically provides 14 dB gain, +33.5 dBm OIP3, and +19 dBm P1dB. The device combines dependable performance with consistent quality to maintain MTBF values exceeding 100 years at mounting temperatures of +85 °C & is housed in a SOT-8 industry-standard SMT lead-free/green/RoHS-compackage.

The AG602-86 consists of Darlington pair ampliff using the high reliability InGaP/GaAs HBT process and only requires DC-blocking capacitors, a and an inductive RF choke for operation.

The broadband MMIC amplifier can be various current and next generation who seek technolog such as GPRS, GSM, CDMA, and CDMA. In the AG602-86 will work for othe various within the DC to 6 GHz frequency and fixed wireless.

Functional Diagram

Funed	Pin No.
~ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\	1
O Bias	3
Dansound	2.4

Typical

1900

12.9

-17

-16

+18.7

+33.5

4.6

2140

12.7

-16

-15

+18.7

+33.3

4.6

900

13.8

-13

-17

+19.0

+33.7

4.5

Specifications (1)

			\sim	\vee /()
Parameter	Units	Min	Ty	XX >
Operational Bandwidth	MHz	DC		B000c
Test Frequency	MHz		(0)	
Gain	dB			\bigcirc
Input Return Loss	dB		Y 17 3	RA
Output Return Loss	dB	20	∑17 <i>{</i>	
Output IP3 (2)	dBm	(0)	+19.	
Output IP2	dBm 🔏		+3(7)	
Output P1dB	dBn/ C			
Noise Figure		> ~ ((G)
Test Frequency	$\mathcal{N}(\mathcal{Q})$. 2	3007.	2
Gain		17(0)	128	713.9
Output IP3 (2)	$\sim 10^{-1}$	(S)		
Output P1dB	/\dBm	(0)	(A)	
Device Voltage	V (C		\$7.16	
Device Curren	[m/		75	
	11/11		, —	

1. Test conditions: T = 25 C,ly Voltage (#6) $R_{bias} = 25$ 50 Ω System

2. 3OIP measured w the suppression of the day of the suppression of th

. The junction era insures a part of MTTF record million hours of usage

Absolute Naximon Rating

Parame	Rating
Operating Case Te Toure	-40 to +85 °C
Storag per co	-55 to +125 °C
DC Le	+7 V
R Power continuous)	+10 dBm
n Tegerature	+250° C

Ordering Information

Units

MHz

dB

dB

dB

dBm

dBm

dΒ

ítput P1dB

Output IP3

Noise Figure

500

14.0

-12

-17

+19.0

+33.9

4.5

Part No.	Description
AG602-86	InGaP HBT Gain Block (lead-tin SOT-86 Pkg)
AG602-86G	InGaP HBT Gain Block (lead-free/green/RoHS-compliant SOT-86 Pkg)

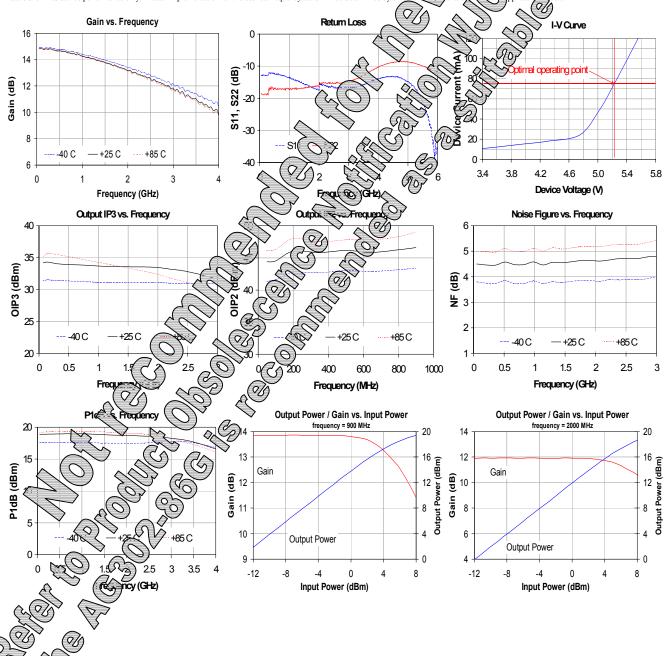
e above any of these parameters may cause permanent damage.

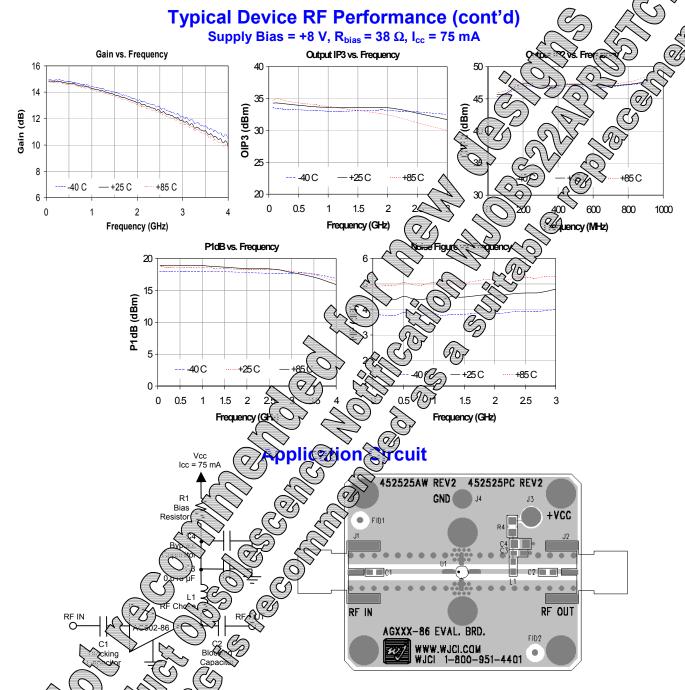
Specifications and information are subject to change without notice

Typical Device RF Performance Supply Bias = +6 V, R_{bias} = 11.2 Ω , I_{cc} = 75 mA

MHz	100	500	900	1900	2140	2400	35(
dB	14.2	14.0	13.8	12.9	12.7	12.4	
dB	-12	-12	-13	-17	-16	-16	
dB	-19	-17	-17	-16	-15	-15	Y
dBm	+18.9	+19.0	+19.0	+18.7	+18.7	C18 1	6) 17
dBm	+34.2	+33.9	+33.7	+33.5	+33.3	(62)	
dB	4.5	4.5	4.5	4.6	4.6		
	dB dB dB dBm dBm	dB 14.2 dB -12 dB -19 dBm +18.9 dBm +34.2	dB 14.2 14.0 dB -12 -12 dB -19 -17 dBm +18.9 +19.0 dBm +34.2 +33.9	dB 14.2 14.0 13.8 dB -12 -12 -13 dB -19 -17 -17 dBm +18.9 +19.0 +19.0 dBm +34.2 +33.9 +33.7	dB 14.2 14.0 13.8 12.9 dB -12 -12 -13 -17 dB -19 -17 -17 -16 dBm +18.9 +19.0 +19.0 +18.7 dBm +34.2 +33.9 +33.7 +33.5	dB 14.2 14.0 13.8 12.9 12.7 dB -12 -12 -13 -17 -16 dB -19 -17 -17 -16 -15 dBm +18.9 +19.0 +19.0 +18.7 +18.7 dBm +34.2 +33.9 +33.7 +33.5 +33.3	dB 14.2 14.0 13.8 12.9 12.7 12.4 dB -12 -12 -13 -17 -16 -16 dB -19 -17 -17 -16 -15 -15 dBm +18.9 +19.0 +19.0 +18.7 +18.7 +18.7 dBm +34.2 +33.9 +33.7 +33.5 +33.3

1. Test conditions: $T = 25^{\circ}$ C, Supply Voltage = +6 V, Device Voltage = 5.16 V, Rbias = 11.2 Ω , Icc = 75 mA typical, 50 Ω System 2. 3OIP measured with two tones at an output power of +2 dBm/tone separated by 10 MHz. The suppression on the largest IM3 pc 3. Data is shown as device performance only. Actual implementation for the desired frequency band will be determined by external transfer of the desired frequency.





1		7 0) \ (
	Refor to		J (0)~	Frequ	ency (MH	z)		
	Designat	500	500	900	1900	2200	2500	3500
	L1	(0) M3	A WH	68 nH	27 nH	22 nH	18 nH	15 nH
	C1, C2, C4	.0.8µF	O pF	100 pF	68 pF	68 pF	56 pF	39 pF

are dependent upon the intended frequency of operation.

on the evaluation board to achieve optimal broadband performance:

Recommen

~	× 0 .7/		
٠,	Ref/ Jy G.	Value / Type	Size
1	LL	39 nH wirewound inductor	0603
	(0)	56 pF chip capacitor	0603
7	C3	0.018 μF chip capacitor	0603
(₽ }}	Do Not Place	
Ľ,	K1	10.0 Ω 1% tolerance	0805
B			•

Decommended Rise Decistor Values

Supply Voltage	R1 value	Size			
6 V	11.2 ohms	0805			
7 V	24.5 ohms	1210			
8 V	38 ohms	1210			
9 V	51 ohms	2010			
10 V	65 ohms	2010			
12 V	91 ohms	2512			

The proper value for R1 is dependent upon the supply voltage and allows for bias stability over temperature. WJ recommends a minimum supply bias of +6 V. A 1% tolerance resistor is recommended.

Specifications and information are subject to change without notice



Typical Device Data

S-Parameters ($V_{device} = +5.16 \text{ V}$, $I_{CC} = 75 \text{ mA}$, $T = 25^{\circ} \text{ C}$, calibrated to device leads)

D I didilieters (device D.10	,,100 ,0111111,	20 0, 000	torated to de ire	e reads)		$\overline{}$	
Freq (MHz)	S11 (dB)	S11 (ang)	S21 (dB)	S21 (ang)	S12 (dB)	S12 (ang)	\$ 0.5	SE (FE)
50	-12.83	177.09	14.80	177.77	-18.80	0.08	(\emptyset)	
250	-12.82	170.56	14.74	169.43	-18.86	-1.92	(10-50) C	Q.20
500	-12.28	160.75	14.65	159.21	-18.96	-3.46	-3.03	7-179.93 (9
750	-12.95	151.18	14.52	149.21	-18.85	-6.03	P 17.02	178.2
1000	-13.42	141.09	14.36	139.36	-18.99	~9(\(\sigma/\delta\)	-1767	-1770
1250	-14.45	130.22	14.20	129.61	-18.80		(2)8/\sigma	<2₹@7
1500	-15.66	118.89	13.96	119.96	-18.74	$\langle \mathcal{O} \rangle$	76/10	717
1750	-16.63	107.21	13.72	110.48	-18.72			0.21
2000	-17.29	91.44	13.45	101.21	-18.72	-17.16	10.05	9 171.46
2250	-16.20	64.73	13.13	92.69	-18.62	19.12	15.30	-157.61
2500	-16.75	61.88	12.95	85.98	-18.62	-200	-152	-166.73
2750	-16.88	58.51	12.66	77.40	-1(5)	-22.1	(CE ()	-178.65
3000	-16.78	58.02	12.38	68.87		Also.	√	164.02
3250	-16.66	58.65	12.09	60.40	(D)	(Alex	3.96	147.18
3500	-15.78	60.29	11.76	52.22	12	-30:43	90, 12.75	131.66
3750	-14.83	64.00	11.38	43.53	-18.13	₩ 33.0 %	-11.49	119.00
4000	-14.00	65.81	11.02	35.47	→-1842	34.9	-10.22	110.33
4250	-13.41	67.18	10.72	(210)	-1	-38	-9.34	103.54
4500	-13.22	67.82	10.44		-12	-(P)	-8.83	98.14
4750	-13.66	68.18	10.12	12.5	-707	-43.83	-8.56	95.06
5000	-14.82	69.02	9.96	5.20		P0 , 47.93	-8.67	93.79
5250	-17.08	69.30	9.80	V-p2.71 ~ C	71.22	-50.61	-9.09	92.99
5500	-20.92	70.38	2.72	-8.45	^ 17.00 /	-52.28	-9.99	93.56
5750	-28.67	80.98	Silis	J -15.72	-16/707	-56.37	-10.93	93.36
6000	-36.06	162.23	(6)	(0).50	6.48	-58.54	-12.13	92.07
			/ O M	\sim			•	

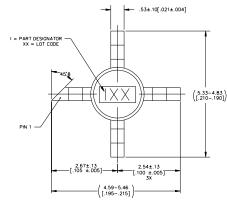
Device S-parameters at an le for down d off website at: http://www.wj.com

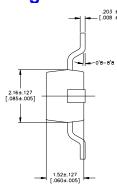


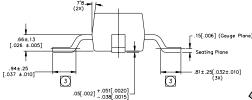
AG602-86 (SOT-86 Package) Mechanical Inform

This package may contain lead-bearing materials. The plating material on the leads is S

Outline Drawing

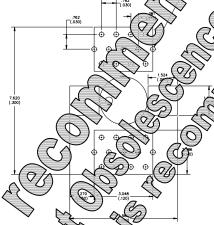






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Thermal Cocific Cona

Oper Tempo 6 +85 °C

Thermal istance 6 165 °C

Junction Tempo 7 165 °C

- 1. The thermal reaches and is a selected from the hottest part of the junction and (pin 2 or 4).
- 2. This correspond to bical biasing condition of +5.16V 5 mA at 100 5 °C case temperature. A minim million hours is achieved for jun merature below 177 °C.

P o ct or ing

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an cel Cifica of for this part are webs: the "Application

MS ESD Rating

oaution! ESD sensitive device.

Stating: Class 0 E: Passes at 150 V

Pst: Human Body Model (HBM) Standard: JEDEC Standard JESD22-A114

ESD Rating: Class II

Value: Passes at 250 V

Test: Charged Device Model (CDM) Standard: JEDEC Standard JESD22-C101

MSL Rating: Level 1

Standard: JEDEC Standard J-STD-020A

Mounting Config. Notes

- Ground / thermal vias are critical for the proper performance of this device. Vias should use a 35mm (#80 / .0155") diameter drill and have a final plated thru diameter of .25 mm (.010").
- Add as much copper as possible to inner and outer layers near the part to ensure optimal thermal performance.
 Mounting screws can be added near the part to fasten the
- Mounting screws can be added near the part to fasten the board to a heatsink. Ensure that the ground / thermal via region contacts the heatsink
- Do not put solder mask on the backside of the PC board in the region where the board contacts the heatsink.
- RF trace width depends upon the PC board material and construction.
- 6. Use 1 oz. Copper minimum.
- All dimensions are in millimeters (inches). Angles are in degrees.



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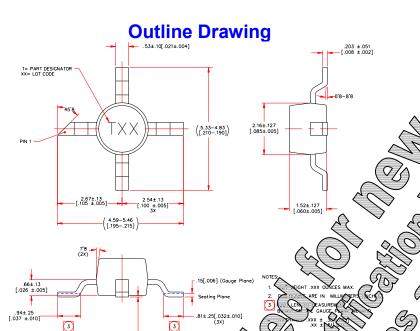
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ESD Rating

aution! ESD sensitive device.

AG602-86G (Green / Lead-free Sot-86 Package) Mechanical

This package is lead-free/Green/RoHS-compliant. It is compatible with both lead-free (maximum 260°C reflection) (maximum 245°C reflow temperature) soldering processes. The plating material on the pins is annealed



Land Patt

Class 1C

Passes at 1000 V min. Human Body Model (HBM) Standard: JEDEC Standard JESD22-A114

ESD Rating: Class IV

Passes at 1000 V min. Value: Charged Device Model (CDM) Test: Standard: JEDEC Standard JESD22-C101

MSL Rating: Level 3 at +260° C convection reflow JEDEC Standard J-STD-020 Standard:

Mounting Config. Notes

- Ground / thermal vias are critical for the proper performance of this device. Vias should use a .35mm (#80 / .0135") diameter drill and have a final plated thru diameter of .25 mm
- 2. Add as much copper as possible to inner and outer layers near the part to ensure optimal thermal performance. Mounting screws can be added near the part to fasten the
- board to a heatsink. Ensure that the ground / thermal via region contacts the heatsink.
- Do not put solder mask on the backside of the PC board in the region where the board contacts the heatsink.
- RF trace width depends upon the PC board material and
- 6. Use 1 oz. Copper minimum.
- All dimensions are in millimeters (inches). Angles are in

-40 to +85 °C Operating Case 206 °C/W Thermal Resis 165 °C Junction Tem

.05[.002] +.051[.0020] -.038[.0015]

Ferenced from the hottest part 1. The thermal 1. Itan Id lead (pin 2 or 4).

typical biasing condition of 5 mA (an 85 °C case temperature. A MTTF of 1 million hours is achieved for ures below 177 °C.